Bulletin PD-20013 Rev.B 10/03

International
IOR Rectifier

IRUD360CW40

FRED

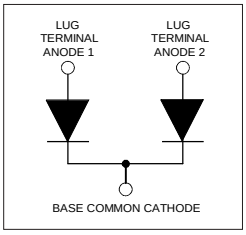
Ultrafast, Soft Recovery Diode

Features

- Ultrafast Recovery
- 150°C Operating Junction Temperature

Benefits

- Reduced RFI and EMI
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count



V_R = 400V

V_F(typ.) = 1.23V

$I_{F(AV)}$ = 350A

Description/ Applications

These diodes are optimized to reduce losses and EMI/ RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not a significant portion of the total losses.

Absolute Maximum Ratings

Parameters (*)		Max	Units
V_R	Cathode-to-Anode Voltage	400	V
$I_{F(AV)}$ @ T_C = 25°C	Continuous Forward Current	350	A
$I_{F(AV)}$ @ T_C = 110°C	Continuous Forward Current	190	
I_{FSM}	Single Pulse Forward Current	1200	
P_D @ T_C = 25°C	Maximum Power Dissipation	570	W
P_D @ T_C = 110°C	Maximum Power Dissipation	180	

Case Styles

IRUD360CW40

TO-244

(*) Per Leg unless otherwise specified

Electrical Characteristics (per Leg) @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Typ	Max	Units	Test Conditions
V_{BR}	Breakdown Voltage,	400	-	-	V	I_R = 100µA
V_{FM}	Forward Voltage	-	1.09	1.27		I_F = 180A
		-	1.23	1.50		I_F = 360A
		-	0.88	0.96		I_F = 180A @ T_J = 150°C
		-	1.04	1.18		I_F = 360A @ T_J = 150°C
I_{RM}	Reverse Leakage Current	-	-	65	µA	V_R = V_R Rated
		-	0.26	1.28	mA	T_J = 150°C, V_R = V_R Rated
L_S	Series Inductance	-	5	-	nH	from top of terminal hole to mounting plane

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Typ	Max	Units	Test Conditions
t_{rr}	Reverse Recovery Time	-	42	69	ns	I_f = 1.0A, dif/dt = 200A/µs, Vr = 30V
		-	74	-		I_f = 180A, dif/dt = 200A/µs, Vr = 200V
		-	171	-		I_f = 180A, dif/dt =200A/µs, Vr =200V @ T_J = 125°C
I_{RRM}	Peak Recovery Current	-	5.1	-	A	I_f = 1.0A, dif/dt = 200A/µs, Vr = 30V
		-	6.6	-		I_f = 180A, dif/dt = 200A/µs, Vr = 200V
		-	15.2	-		I_f = 180A, dif/dt =200A/µs, Vr =200V @ T_J = 125°C
Q_{rr}	Reverse Recovery Charge	-	126	-	nC	I_f = 1.0A, dif/dt = 200A/µs, Vr = 30V
		-	243	-		I_f = 180A, dif/dt = 200A/µs, Vr = 200V
		-	1295	-		I_f = 180A, dif/dt =200A/µs, Vr =200V @ T_J = 125°C

Thermal - Mechanical Characteristics

	Parameters		Min	Typ	Max	Units
T_J	Max. Junction Temperature Range		- 40	-	150	°C
T_{Stg}	Max. Storage Temperature Range		- 40	-	150	
R_{thJC}	Thermal Resistance, Junction to Case	Per Leg	-	-	0.22	°C/W
	Thermal Resistance, Junction to Case	Per Module	-	-	0.11	
R_{thCS}	Thermal Resistance, Case to Heatsink flat greased surface		-	0.10	-	
Wt	Weight		-	68 (2.4)	-	g (oz)
T	Mounting Torque		30 (3.4)	-	40 (4.6)	lbf.in
	Mounting Torque Center Hole		12 (1.4)	-	18 (2.1)	(N.m)
	Terminal Torque		30 (3.4)	-	40 (4.6)	
	Vertical Pull		-	-	80	lbf.in
	2 inch. Lever Pull		-	-	35	

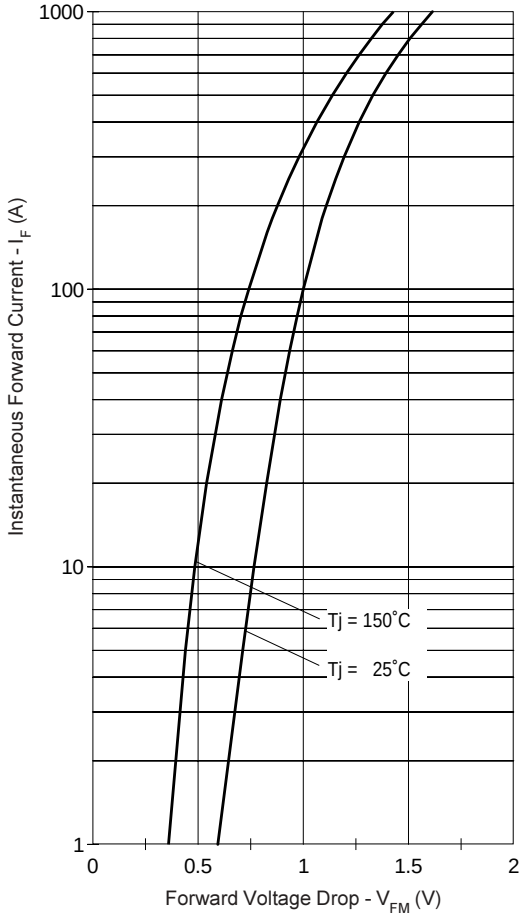


Fig. 1 - Typical Forward Voltage Drop
vs. Instantaneous Forward Current (per Leg)

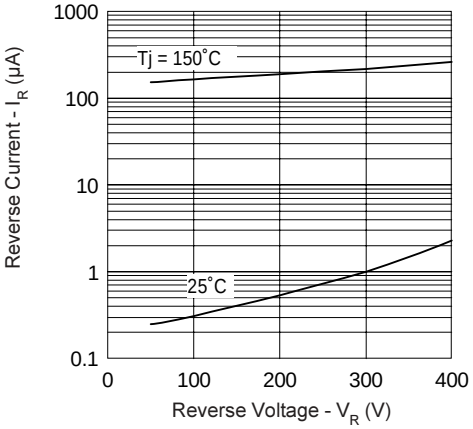


Fig. 2 - Typical Reverse Current vs. Reverse
Voltage (per Leg)

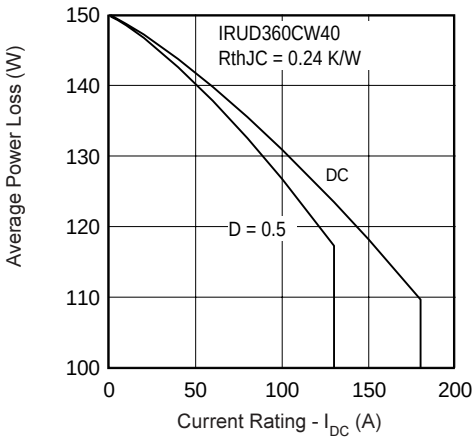


Fig. 3 - Max. Current Rating Capability
(per Module)

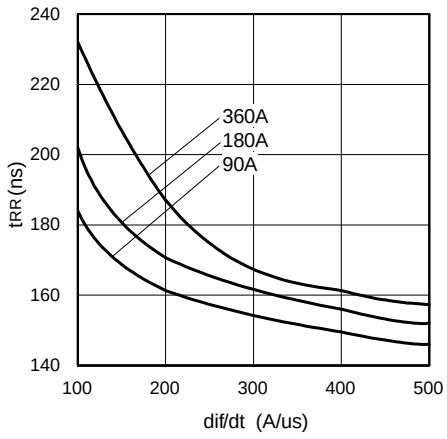


Fig. 4 - Typical Reverse Recovery vs. di_f/dt
Tj = 125°C (per Leg)

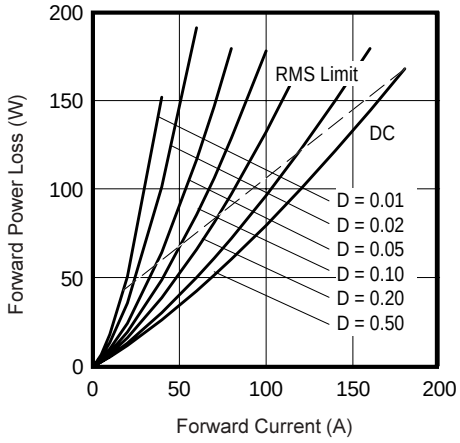


Fig. 5 - Forward Power Loss Characteristics

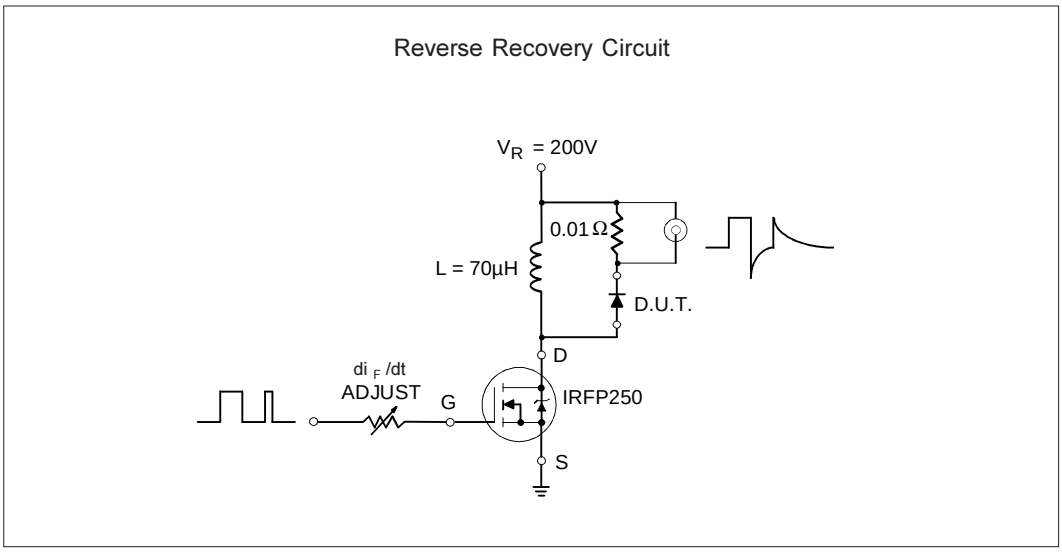
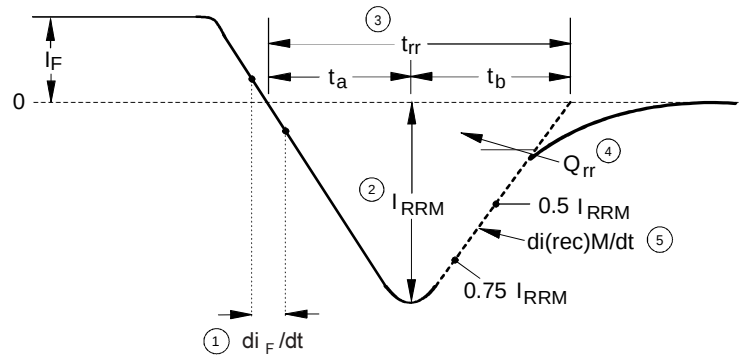


Fig. 6- Reverse Recovery Parameter Test Circuit



1. di_F/dt - Rate of change of current through zero crossing

2. I_{RRM} - Peak reverse recovery current

3. t_{rr} - Reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current

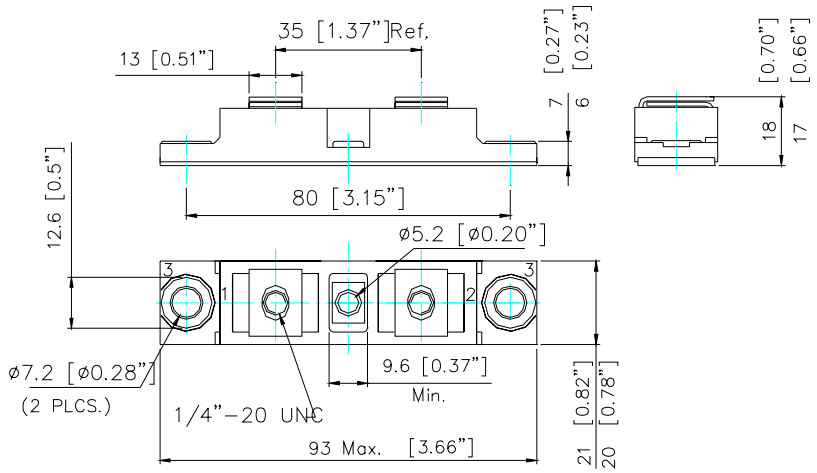
4. Q_{rr} - Area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

5. $di_{(rec)M}/dt$ - Peak rate of change of current during t_b portion of t_{rr}

Fig. 7 - Reverse Recovery Waveform and Definitions

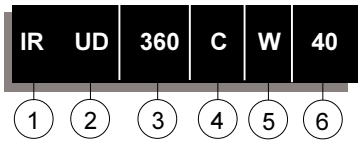
Outline Table



Conforms to JEDEC Outline TO-244
Dimensions in millimeters and (inches)

Ordering Information Table

Device Code



1	-	**International Rectifier**	
2	-	Type of Device Indicator:	**UD = HEXFRED Gen.2**
3	-	Current Rating indicator x1 :	**360 = 360A**
4	-	Circuit Configuration Indicator:	**C = Common Cathode**
5	-	Type of Device Indicator:	**W = TO-244 Wire Bondable Not Isolated**
6	-	Voltage Rating indicator x10 :	**40 = 400V**

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

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